- Designed for Complementary Use with TIP135, TIP136 and TIP137
- 70 W at 25°C Case Temperature
- 8 A Continuous Collector Current
- Minimum h_{FE} of 1000 at 4 V, 4 A

Pin 2 is in electrical contact with the mounting base.

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absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT
	TIP130		60	
Collector-base voltage (I _E = 0)	TIP131	V_{CBO}	80	V
	TIP132		100	
	TIP130		60	
Collector-emitter voltage (I _B = 0)	TIP131	V_{CEO}	80	V
	TIP132		100	ı
Emitter-base voltage			5	V
Continuous collector current			8	Α
Peak collector current (see Note 1)			12	Α
Continuous base current			0.3	Α
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		P _{tot}	70	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)		P _{tot}	2	W
Unclamped inductive load energy (see Note 4)			75	mJ
Operating junction temperature range			-65 to +150	°C
Storage temperature range			-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds			260	°C

- NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%.$
 - 2. Derate linearly to 150°C case temperature at the rate of 0.56 W/°C.
 - 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
 - 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = 5 mA, R_{BE} = 100 Ω , $V_{BE(off)}$ = 0, R_{S} = 0.1 Ω , V_{CC} = 20 V.



TIP130, TIP131, TIP132 NPN SILICON POWER DARLINGTONS

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electrical characteristics at 25°C case temperature

PARAMETER TEST CONDITIONS			MIN	TYP	MAX	UNIT			
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = 30 mA	I _B = 0	(see Note 5)	TIP130 TIP131 TIP132	60 80 100			V
I _{CEO}	Collector-emitter cut-off current	$V_{CE} = 30 \text{ V}$ $V_{CE} = 40 \text{ V}$ $V_{CE} = 50 \text{ V}$	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$		TIP130 TIP131 TIP132	100		0.5 0.5 0.5	mA
I _{CBO}	Collector cut-off current	_	$I_{E} = 0$	$T_C = 100$ °C $T_C = 100$ °C $T_C = 100$ °C	TIP130 TIP131 TIP132 TIP130 TIP131 TIP132			0.2 0.2 0.2 1 1	mA
I _{EBO}	Emitter cut-off current	V _{EB} = 5 V	I _C = 0					5	mA
h _{FE}	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$	$I_C = 1 A$ $I_C = 4 A$	(see Notes 5 and 6)		500 1000		15000	
V _{CE(sat)}	Collector-emitter saturation voltage	$I_B = 16 \text{ mA}$ $I_B = 30 \text{ mA}$	$I_C = 4 A$ $I_C = 6 A$	(see Notes 5 and 6)				2 3	V
V_{BE}	Base-emitter voltage	V _{CE} = 4 V	I _C = 4 A	(see Notes 5 and	d 6)			2.5	V
C _{obo}	Output capacitance	V _{CB} = 10 V	I _E = 0					200	pF
V _{EC}	Parallel diode forward voltage	I _E = 8 A	I _B = 0	(see Notes 5 and	d 6)			3.5	٧

NOTES: 5. These parameters must be measured using pulse techniques, t_p = 300 μ s, duty cycle \leq 2%.

thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.78	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

^{6.} These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN COLLECTOR CURRENT TCS130AA 50000 $T_c = -40^{\circ}C$ 25°C $T_c = 100$ °C h_{FE} - Typical DC Current Gain 10000 1000 4 V = 300 µs, duty cycle < 2% 100 0.5 1-0 10 Ic - Collector Current - A

Figure 1.

COLLECTOR-EMITTER SATURATION VOLTAGE

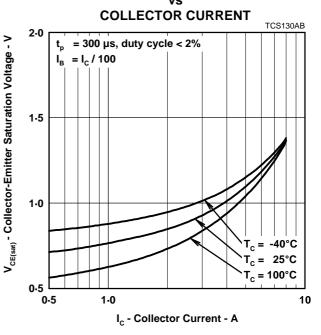
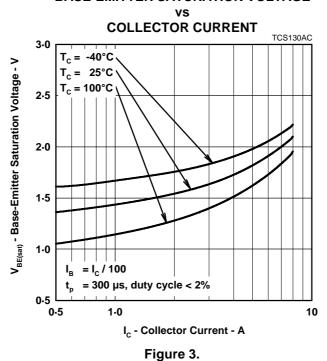


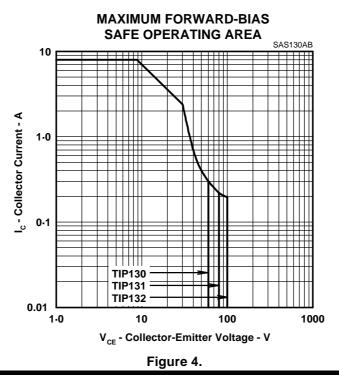
Figure 2.

BASE-EMITTER SATURATION VOLTAGE



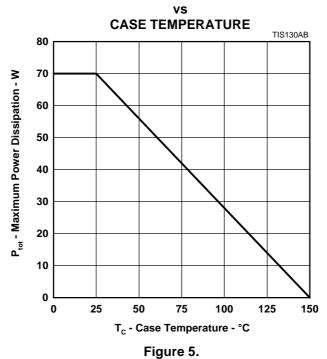
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THERMAL INFORMATION

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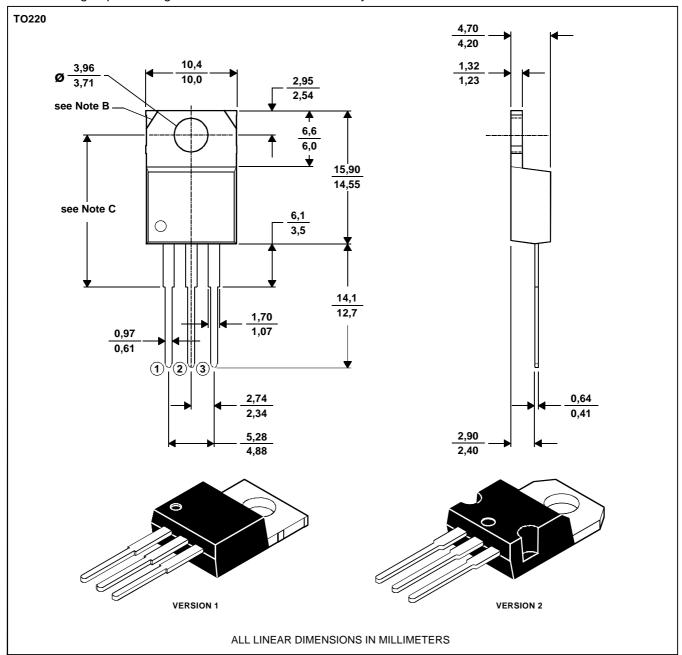
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MECHANICAL DATA

TO-220

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.

- B. Mounting tab corner profile according to package version.
- C. Typical fixing hole centre stand off height according to package version. Version 1, 18.0 mm. Version 2, 17.6 mm.

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PRODUCT INFORMATION

TIP130, TIP131, TIP132 NPN SILICON POWER DARLINGTONS

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